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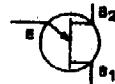
## PN Unijunction Transistors Silicon Unijunction Transistors

... designed for pulse and timing circuits, sensing circuits, and thyristor trigger circuits.

- Low Peak-Point Current —  $I_P = 0.4 \mu\text{A}$  Max
- Low Emitter Reverse Current —  $I_{EO} = 50 \text{ nA}$  Max
- Fast Switching

**2N4851  
thru  
2N4853**

PN UJTs



CASE 22A-01

\*MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

| Rating                               | Symbol     | Value       | Unit  |
|--------------------------------------|------------|-------------|-------|
| RMS Power Dissipation, Note 1        | $P_D$      | 300         | mW    |
| RMS Emitter Current                  | $I_E$      | 50          | mA    |
| Peak-Pulse Emitter Current, Note 2   | $I_E$      | 1.8         | Amp   |
| Emitter Reverse Voltage              | $V_{B2E}$  | 30          | Volts |
| Interbase Voltage, Note 3            | $V_{B2B1}$ | 36          | Volts |
| Operating Junction Temperature Range | $T_J$      | -65 to +125 | °C    |
| Storage Temperature Range            | $T_{Stg}$  | -65 to +200 | °C    |

\*Indicates JEDEC Registered Data.

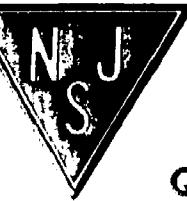
Notes: 1. Derate 3 mW/°C increase in ambient temperature.

2. Duty cycle < 1%, PRR = (see Figure 8).

3. Based upon power dissipation at  $T_A = 25^\circ\text{C}$ .

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**Quality Semi-Conductors**



## 2N4861 thru 2N4863

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

| Rating   | Fig. No. | Symbol                | Min          | Typ         | Max          | Unit          |
|--|----------|-----------------------|--------------|-------------|--------------|---------------|
| *Intrinsic Standoff Ratio, Note 1<br>( $V_{B2B1} = 10 \text{ V}$ )   | 4, 8     | $\eta$                | 0.66<br>0.70 | —           | 0.78<br>0.85 | —             |
| *Interbase Resistance<br>( $V_{B2B1} = 3 \text{ V}, I_E = 0$ )   | 11, 12   | $r_{BB}$              | 4.7          | —           | 9.1          | k ohms        |
| *Interbase Resistance Temperature Coefficient<br>( $V_{B2B1} = 3 \text{ V}, I_E = 0, T_A = -65 \text{ to } +125^\circ\text{C}$ ) | 12       | $\alpha_{BB}$         | 0.2          | —           | 0.8          | %/°C          |
| Emitter Saturation Voltage, Note 2<br>( $V_{B2B1} = 10 \text{ V}, I_E = 50 \text{ mA}$ )   |          | $V_{EB1(\text{sat})}$ | —            | 2.5         | —            | Volts         |
| Modulated Interbase Current<br>( $V_{B2B1} = 10 \text{ V}, I_E = 50 \text{ mA}$ )  |          | $I_{B2(\text{mod})}$  | —            | 15          | —            | mA            |
| *Emitter Reverse Current<br>( $V_{B2E} = 30 \text{ V}, I_B1 = 0$ )   | 7        | $I_{EB20}$            | —<br>—       | —<br>—      | 0.1<br>0.05  | $\mu\text{A}$ |
| *Peak-Point Emitter Current<br>( $V_{B2B1} = 25 \text{ V}$ )   | 9, 10    | $I_P$                 | —<br>—       | —<br>—      | 2<br>0.4     | $\mu\text{A}$ |
| *Valley-Point Current, Note 2<br>( $V_{B2B1} = 20 \text{ V}, R_{B2} = 100 \text{ ohms}$ )  | 13, 14   | $I_V$                 | 2<br>4<br>6  | —<br>—<br>— | —            | mA            |
| *Base-One Peak Pulse Voltage   | 3, 17    | $V_{OB1}$             | 3<br>5<br>6  | —<br>—<br>— | —            | Volts         |
| *Maximum Frequency of Oscillation  | 8        | $f_{(\text{max})}$    | —            | 0.25        | —            | MHz           |

\*Indicates JEDEC Registered Data.

Notes: 1.  $\eta$ , Intrinsic standoff ratio, is defined in terms of the peak-point voltage,  $V_P$ , by means of the equation:  $V_P = \eta V_{B2B1} + V_F$ , where  $V_F$  is about 0.49 volt at  $25^\circ\text{C}$  @  $I_E = 10 \mu\text{A}$  and decreases with temperature at about  $2.5 \text{ mV}/^\circ\text{C}$ . The test circuit is shown in Figure 4. Components  $R_1$ ,  $C_1$ , and the UJT form a relaxation oscillator; the remaining circuitry serves as a peak-voltage detector. The forward drop of Diode  $D_1$  compensates for  $V_F$ . To use, the "cal" button is pushed, and  $R_3$  is adjusted to make the current meter,  $M_1$ , read full scale. When the "cal" button is released, the value of  $\eta$  is read directly from the meter, if full scale on the meter reads 1.

2. Use pulse techniques:  $PW \approx 300 \mu\text{s}$ , duty cycle  $\leq 2\%$  to avoid internal heating, which may result in erroneous readings.

FIGURE 1 – UNIJUNCTION  
TRANSISTOR  
SYMBOL AND NOMENCLATURE

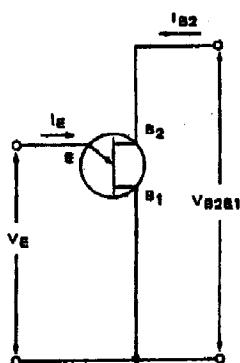


FIGURE 2 – STATIC Emitter  
CHARACTERISTICS CURVES

